Yuheng Chen

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OBJECTIVE

4th year ECE Ph.D., seeking a full-time summer internship to apply photonics/optics simulation and machine learning skills.

EDUCATION

Purdue University Advisor: Dr. Vladimir M. Shalaev, Dr. Alexandra Boltasseva	West Lafayette, IN
Ph.D. in Electrical and Computer Engineering (with Ross Fellowship)	08/2021 ~ 05/2026
NanoML Team leader President of IEEE Photonics Society Student Chapter Ex-Vice President of S	SPIE Student Chapter
University of Science and Technology of China (USTC)	Hefei, China
M.S. in Optical Engineering (Honor)	09/2018 ~ 06/2021
Hohai University	Nanjing, China
B.S. in Mechanical and Automation Engineering (Honor)	09/2014 ~ 06/2018

QUALIFICATIONS

Programming: Proficient in Python, PyTorch, TensorFlow, Java, JavaScript, C/C++, Matlab for machine learning, multimodal model, computer vision, image segmentation, data augmentation, regression analysis, quantum computation. Simulation & Design: Lumerical (FDTD/RCWA), Comsol, KLayout, Zemax, LabVIEW, Ansys-FEA, SolidWorks, AutoCAD. **Device fabrication:** 6 years of cleanroom experience in nanodevice prototype design and fabrication: process optimization, lithographing (EBL, UV exposure), etching (RIBE, IBE, ICP, wet etching), AFM/SEM/microscopy optical characterization.

INDUSTRIAL EXPERIENCE

KLA Corporation | Milpitas, CA

Machine Learning Algorithm Engineer Intern

1. Neural network solution for KLA AcuShape[#] chip architecture software

- Developed neural network to realize geometry critical dimension (CD) and spectra prediction/validation for Samsung V-NAND devices, substituting RCWA numerical method in the design loop.
- Designed bidirectional-training networks to accomplish software library generation with an 80% smaller training dataset and better linearity performance.
- 2. Investigate effective device degree-of-freedom (DOF) reduction via generative AI
- Built up a variational autoencoder-based model to effectively reconstruct and sample large DOF geometry critical dimension (CD) of semiconductor devices into decreased DOF in compressed latent space.
- Perturbed compressed DOF CDs during high-quality spectra output regression optimization and decreased 70% of regression iterations/simulation resource usage.

Xingyu Automotive Lighting Systems | Changzhou, China

Optical Engineer Intern

High-pixel digital lighting unit design

- Applied 3D modeling and optical trace simulations to design high-pixel, independently adjustable LED light matrices.
- Developed customized lighting projection functions for driving assistance in BMW lighting system team.

ACADEMIC EXPERIENCE

Machine learning for semiconductor

1. Authentication in chip encryption through deep engine-based processing of tampered optical responses

- Designed a RAPTOR (Residual, Attention-based Processing of Tampered Optical Response) discriminator for identifying adversarial tampering of an optical, physical unclonable function based on a random array of gold nanoparticles embedded in semiconductor packaging.
- Extracted features of gold nanoparticles from 1000 dark-field images in just 27 ms and verified their authenticity using RAPTOR in 80 ms with 97.6% accuracy under difficult adversarial tampering conditions.

Supervisors: Dr. Phillip Atkins, Dr. Jinchuan Shi

05/2023 ~ 08/2023

09/2017 ~ 05/2018

- (1) B. Wilson[†], **Y. Chen**[†], and A. V. Kildishev, et al, 'Authentication through residual attention-based processing of tampered optical responses', *Advanced Photonics*, 6(5), 056002-056002 (2024). [Paper] (*Patent pending*)
- (2) B. Wilson[†], **Y. Chen**[†], and A. V. Kildishev, et al, 'Machine learning assisted optical authentication of chip tampering', *SPIE Optics + Photonics, Metamaterials, Metadevices, and Metasystems Conference*, 13113-16 (2024).
- (3) SPIE featured news on our work: 'AI-powered optical detection to thwart counterfeit chips, researchers developed a robust optical anticounterfeit method for semiconductor devices'. [News] (*Reported/interviewed by over 20 media globally*)

Inverse design / machine learning for device optimization (with Microsoft, QuEra, and Oak Ridge National Lab)

- 1. Advancing photonic design with topological latent diffusion generative model
- Developed topology optimization (TO) based deep generative model: Topological Latent Diffusion Model (TLDM), to realize high-quality photonics device inverse design.
- Applied efficiency prediction model-embedded conditional U-net and demonstrated substantial efficiency improvement compared with state-of-the-art generative model benchmarks.
- 2. Quantum-inspired latent polynomial unconstrained binary optimization (PUBO) for device co-design
- Mapped device optimization problem into latent PUBO energy model to enforce the combinatorial optimization problem to the data optimization problem.
- Introduced variational neural annealing implemented through recurrent neural networks (RNNs) to solve PUBO in energy state, significantly outperformed simulated annealing and quantum annealing on sampling time and device efficiency.
- 3. Multimodal model for prompt-guided integrated photonics design
- Utilized stable diffusion model for a device feature description text-device topology image multimodal dual-training.
- Combined ChatGPT API with the packaged trained model to realize an interactive LLM-empowered prompt-guided photonics device design interface.
- (1) M. Bezick[†], **Y. Chen**[†], B. Wilson, A. V. Kildishev, V. M. Shalaev, and A. Boltasseva, 'Latent diffusion models for global optimization in inverse design', *Nature Communications*, in review.
- (2) M. Bezick, B. Wilson, V. Iyer, **Y. Chen**, V. M. Shalaev, S. Kais, A. Boltasseva, and B. Lackey, 'Pearson-correlated variational neural annealing for latent PUBO optimization', *Advanced Optical Materials*, in review (invited).
- (3) **Y. Chen**, M. Bezick, and V. M. Shalaev, et al, 'Advancing photonic design with topological latent diffusion generative model', *Optica Frontiers in Optics + Laser Science Conference* (2024).
- (4) B. Wilson, Y. Chen, S. Kais, A. V. Kildishev, V. M. Shalaev, and A. Boltasseva, 'Empowering quantum 2.0 devices and approaches with machine learning', *Optica Quantum 2.0 Conference and Exhibition*, QTu2A.13 (2022). [Paper]
- (5) **Y. Chen**, Y. Liu, W. Cai, and A. Boltasseva, 'Generative models for photonics device design and optimization', in preparation. (*leading the collaboration with GeorgiaTech and Northeastern, supported by 1.5 million NSF funding*)

Nanophotonics and Nanofabrication of metasurface

- 1. Integrated plasmonic-enhanced 2D semiconductor light-emitting device
- Realized first experimental transfer of 2D Transition-metal dichalcogenides materials on plasmonic nano-terrace morphology.
- Generated 12-fold light emission enhancement with flexible manipulation feature, LSPR (Localized surface plasmon resonance) enhancement mechanism verified through FDTD simulation.
- 2. Self-organized lithography-free nanodevice fabrication with tunable optical anisotropy
- Implemented lithography-free self-organized metal co-deposition ion etching nanofabrication method as team leader, realizing 3-fold aspect ratio promotion.
- Demonstrated outstanding tunable optical anisotropy feature in polarization, fitting well with RCWA simulation.
- (1) L. Mascaretti, **Y. Chen**, O. Henrotte, O. Yesilyurt, V. M. Shalaev, A. Naldoni, and A. Boltasseva, 'Designing metasurface for efficient solar energy conversion', *ACS Photonics*, 10(12), 4079-4103 (2023). [Paper]
- (2) **Y. Chen**, H. Li, and Y. Liu, et al, 'Monolayer excitonic semiconductors integrated with Au quasi-periodic nanoterrace morphology on fused silica substrates for light-emitting devices', *ACS Applied Nano Materials*, 4, 84-93 (2021). [Paper]
- (3) **Y. Chen**, M. Cai, H. Zang, H. Chen, S. Kroker, Y. Lu, Y. Liu, F. Frost, and Y. Hong, 'Optical anisotropy of selforganized gold quasi-blazed nanostructures based on a broad ion beam', *Applied Optics*, 60, 505-512 (2021). [Paper]
- (4) **Y. Chen**, M. Cai, K. Qiu, and Y. Hong, 'Optical anisotropy of metal nanowire arrays on fused silica surface', *Proceedings of SPIE*, 114271N (2020). [Paper]